

Product data sheet

1. General description

Planar passivated AC Thyristor Triac power switch in a SOT186A (TO-220F) "full pack" plastic package with self-protective capabilities against low and high energy transients. This "series COT" triac will commutate the full RMS current at the maximum rated junction temperature ($T_{j(max)} = 150$ °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- · High junction operating temperature capability
- High minimum I_{GT} for guaranteed immunity to gate noise
- Full cycle AC conduction
- Isolated mounting base package
- · Less sensitive gate for high noise immunity
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Safe clamping capability for low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls
- · Applications subject to high temperature

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | |
|---------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 104 \text{ °C}$; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u> | - | - | 8 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t _p = 20 ms; Fig. 4; Fig. 5 | - | - | 80 | A |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|-----|-----|-----|------|
| | | full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms | - | - | 88 | A |
| Tj | junction temperature | | - | - | 150 | °C |
| V _{PP} | peak pulse voltage | T _j = 25 °C; non-repetitive, off-state; Fig. 6 | - | - | 2 | kV |
| Static chara | acteristics | · | | | | |
| I _{GT} | gate trigger current | V_D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; Fig. 8 | 5 | - | 30 | mA |
| | | V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u> | 5 | - | 30 | mA |
| | | V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u> | 5 | - | 30 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u> | - | - | 35 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 11</u> | - | 1.3 | 1.5 | V |
| V _{CL} | clamping voltage | I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C | 850 | - | - | V |
| Dynamic cl | naracteristics | | | | · | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 600 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T_j = 150 °C; $I_{T(RMS)}$ = 8 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit | 3 | - | - | A/ms |

5. Pinning information

| Table 2. | Pinning inf | formation | | |
|----------|-------------|-------------------------|--------------------|-----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | СМ | common | mb | LD |
| 2 | LD | load | | |
| 3 | G | gate | | G—/ |
| mb | n.c. | mounting base; isolated | TO-220F (SOT186A) | CM 003aaf296 |

6. Ordering information

| Table 3. Ordering information | | | | | | | | |
|-------------------------------|---------|---|---------|--|--|--|--|--|
| Type number | Package | | | | | | | |
| | Name | Description | Version | | | | | |
| ACTT8X-800C0T | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A | | | | | |

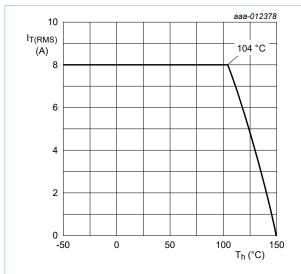
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7. Limiting values

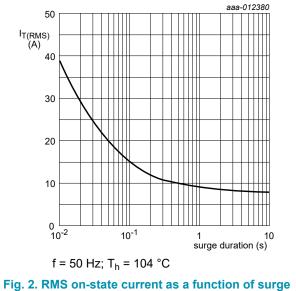
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--|--|-----|-----|------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _h ≤ 104 °C; <u>Fig. 1; Fig. 2;</u> <u>Fig. 3</u> | - | 8 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5 | - | 80 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 88 | А |
| l ² t | I ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 32 | A²s |
| dl _T /dt | rate of rise of on-state current | I _G = 0.2 A | - | 100 | A/µs |
| I _{GM} | peak gate current | t = 20 µs | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 150 | °C |
| V _{PP} | peak pulse voltage | T _j = 25 °C; non-repetitive, off-state; <u>Fig. 6</u> | - | 2 | kV |

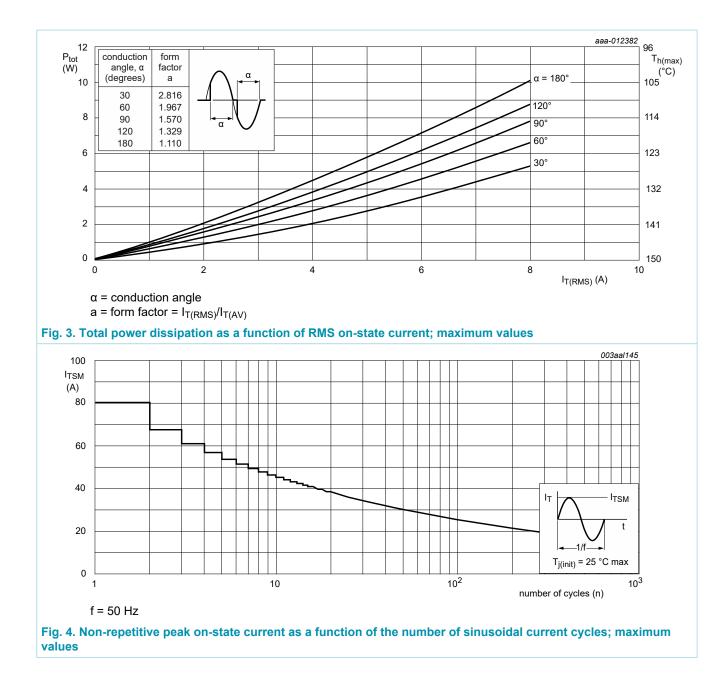






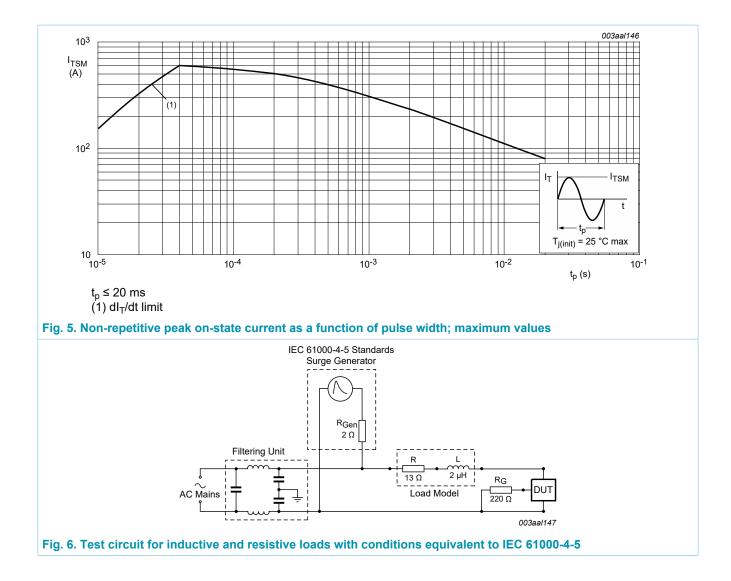


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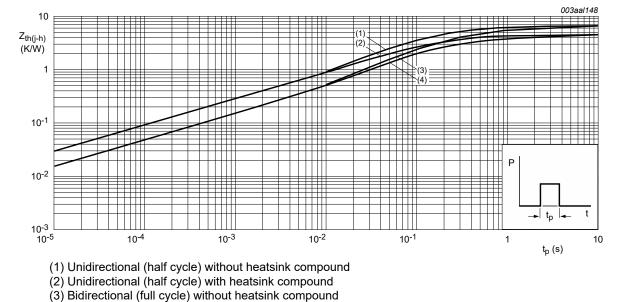


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8. Thermal characteristics

| Symbol | Parameter | Conditions | N | Min | Тур | Max | Unit |
|----------------------|--|--|---|-----|-----|-----|------|
| R _{th(j-h)} | thermal resistance from junction to | full or half cycle with heatsink compound; Fig. 7 | - | | - | 4.5 | K/W |
| | heatsink | full or half cycle without heatsink compound; Fig. 7 | - | | - | 6.5 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient free air | in free air | - | | 55 | - | K/W |



(4) Bidirectional (full cycle) with heatsink compound

Fig. 7. Transient thermal impedance from junction to heatsink as a function of pulse width

9. Isolation characteristics

| Table 6. Isolat | ion characteristics | | | | | |
|------------------------|-----------------------|--|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{isol(RMS)} | RMS isolation voltage | sinusoidal waveform; from all pins to external heatsink; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from LD pin to external heatsink; f = 1 MHz; T_h = 25 °C | - | 10 | - | pF |

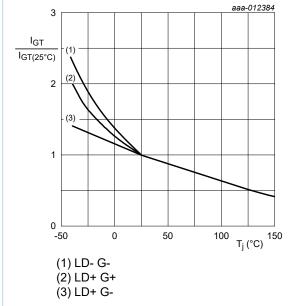
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10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|-----|------|-----|------|
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u> | 5 | - | 30 | mA |
| | | V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u> | 5 | - | 30 | mA |
| | | V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u> | 5 | - | 30 | mA |
| l _L la | latching current | V_D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u> | - | - | 50 | mA |
| | | V_D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 70 | mA |
| | | V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 50 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u> | - | - | 35 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 11</u> | - | 1.3 | 1.5 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 12 | - | 0.8 | 1 | V |
| | | V _D = 400 V; I _T = 100 mA; T _j = 150 °C; Fig. 12 | 0.2 | 0.45 | - | V |
| I _D | off-state current | V _D = 800 V; T _j = 25 °C | - | - | 10 | μA |
| | | V _D = 800 V; T _j = 150 °C | - | - | 2 | mA |
| V _{CL} | clamping voltage | I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C | 850 | - | - | V |
| Dynamic ch | naracteristics | · · · · · | 1 | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 600 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | $V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$ | 3 | - | - | A/ms |

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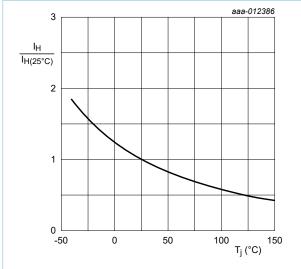
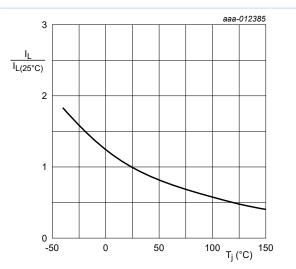
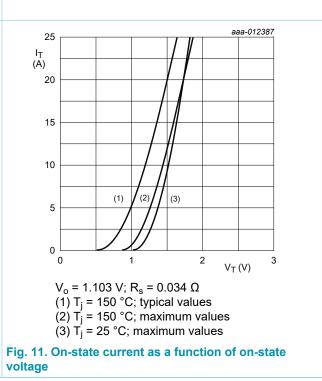


Fig. 10. Normalized holding current as a function of junction temperature

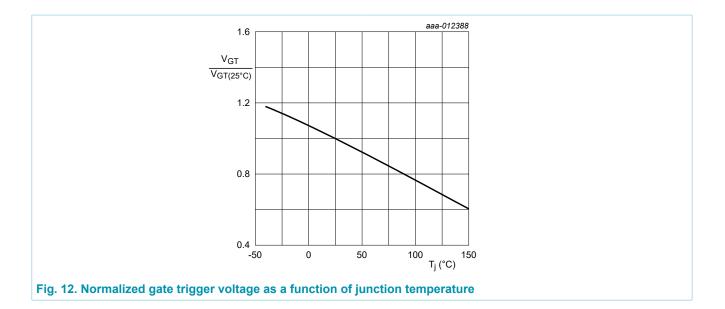






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11. Package outline

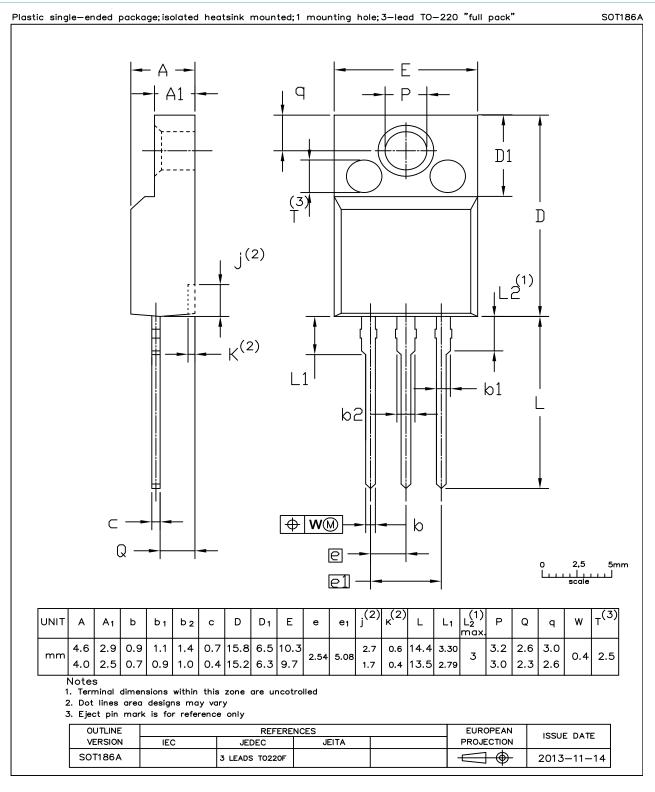


Fig. 13. Package outline TO-220F (SOT186A)

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| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---|
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